

NST3906DP6T5G

Dual General Purpose Transistor

The NST3906DP6T5G device is a spin-off of our popular SOT-23/SOT-323/SOT-563 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-963 six-leaded surface mount package. By putting two discrete devices in one package, this device is ideal for low-power surface mount applications where board space is at a premium.

Features

- h_{FE} , 100–300
- Low $V_{CE(sat)}$, ≤ 0.4 V
- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- This is a Pb-Free Device

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	–40	V
Collector–Base Voltage	V_{CBO}	–40	V
Emitter–Base Voltage	V_{EBO}	–5.0	V
Collector Current – Continuous	I_C	–200	mA
Electrostatic Discharge	HBM MM	ESD Class 2 B	

THERMAL CHARACTERISTICS

Characteristic (Single Heated)	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above 25°C (Note 1)	P_D	240 1.9	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	520	$^\circ\text{C/W}$
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above 25°C (Note 2)	P_D	280 2.2	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	446	$^\circ\text{C/W}$
Characteristic (Dual Heated) (Note 3)	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above 25°C (Note 1)	P_D	350 2.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	357	$^\circ\text{C/W}$
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above 25°C (Note 2)	P_D	420 3.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	297	$^\circ\text{C/W}$
Junction and Storage Temperature Range	T_J, T_{stg}	–55 to +150	$^\circ\text{C}$

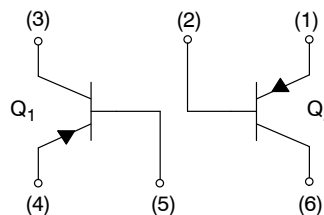
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ 100 mm², 1 oz. copper traces, still air.
2. FR-4 @ 500 mm², 1 oz. copper traces, still air.
3. Dual heated values assume total power is sum of two equally powered channels.

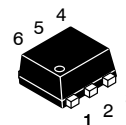


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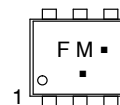


NST3906DP6T5G



SOT-963
CASE 527AD
PLASTIC

MARKING DIAGRAM



F = Device Code
M = Date Code
▪ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
NST3906DP6T5G	SOT-963 (Pb-Free)	8000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage (Note 4) (I _C = 1.0 mAdc, I _B = 0)	V _{(BR)CEO}	–40	–	V
Collector–Base Breakdown Voltage (I _C = 10 μAdc, I _E = 0)	V _{(BR)CBO}	–40	–	V
Emitter–Base Breakdown Voltage (I _E = 10 μAdc, I _C = 0)	V _{(BR)EBO}	–5.0	–	V
Collector Cutoff Current (V _{CE} = 30 Vdc, V _{EB} = 3.0 Vdc)	I _{CEX}	–	–50	nA

ON CHARACTERISTICS (Note 4)

DC Current Gain (I _C = –0.1 mA, V _{CE} = –1.0 V) (I _C = –1.0 mA, V _{CE} = –1.0 V) (I _C = –10 mA, V _{CE} = –1.0 V) (I _C = –50 mA, V _{CE} = –1.0 V) (I _C = –100 mA, V _{CE} = –1.0 V)	h _{FE}	60 80 100 60 30	– – 300 – –	–
Collector–Emitter Saturation Voltage (I _C = –10 mA, I _B = –1.0 mA) (I _C = –50 mA, I _B = –5.0 mA)	V _{CE(sat)}	– –	–0.25 –0.4	V
Base–Emitter Saturation Voltage (I _C = –10 mA, I _B = –1.0 mA) (I _C = –50 mA, I _B = –5.0 mA)	V _{BE(sat)}	–0.65 –	–0.85 –0.95	V

SMALL–SIGNAL CHARACTERISTICS

Current–Gain – Bandwidth Product (I _C = 10 mAdc, V _{CE} = 20 Vdc, f = 100 MHz)	f _T	250	–	MHz
Output Capacitance (V _{CB} = –5.0 V, I _E = 0 mA, f = 1.0 MHz)	C _{obo}	–	4.5	pF
Input Capacitance (V _{EB} = –0.5 V, I _E = 0 mA, f = 1.0 MHz)	C _{ibo}	–	10.0	pF
Noise Figure (V _{CE} = –5.0 V, I _C = –100 μA, R _S = 1.0 k Ω, f = 1.0 kHz)	NF	–	4.0	dB

SWITCHING CHARACTERISTICS

Delay Time (V _{CC} = –3.0 V, V _{BE} = 0.5 V)	t _d	–	35	ns
Rise Time (I _C = –10 mA, I _{B1} = –1.0 mA)	t _r	–	35	
Storage Time (V _{CC} = –3.0 V, I _C = –10 mA)	t _s	–	250	ns
Fall Time (I _{B1} = I _{B2} = –1.0 mA)	t _f	–	50	

4. Pulse Test: Pulse Width ≤ 300 μs; Duty Cycle ≤ 2.0%.

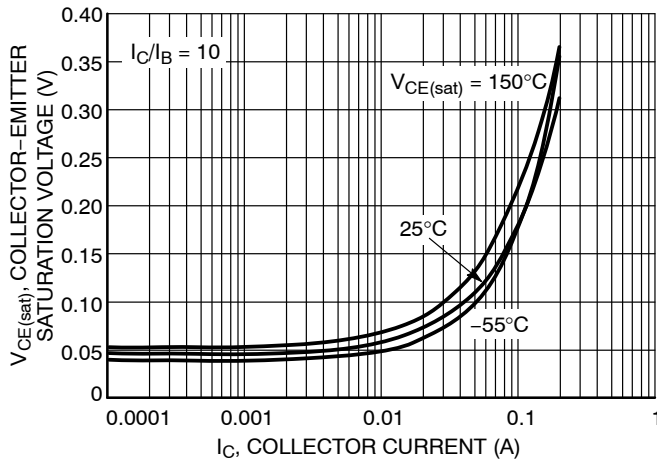


Figure 1. Collector Emitter Saturation Voltage vs. Collector Current

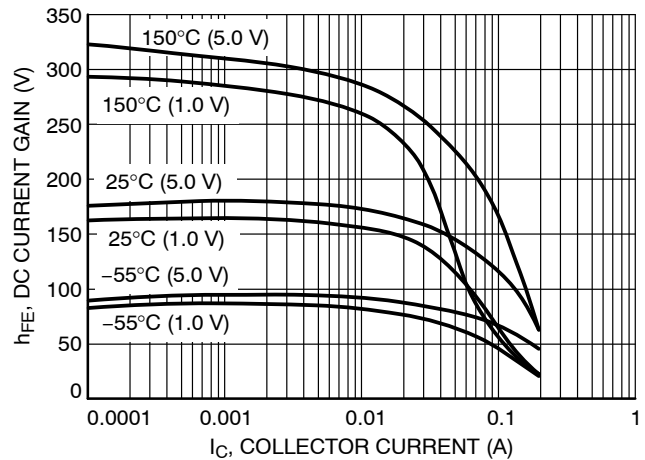


Figure 2. DC Current Gain vs. Collector Current

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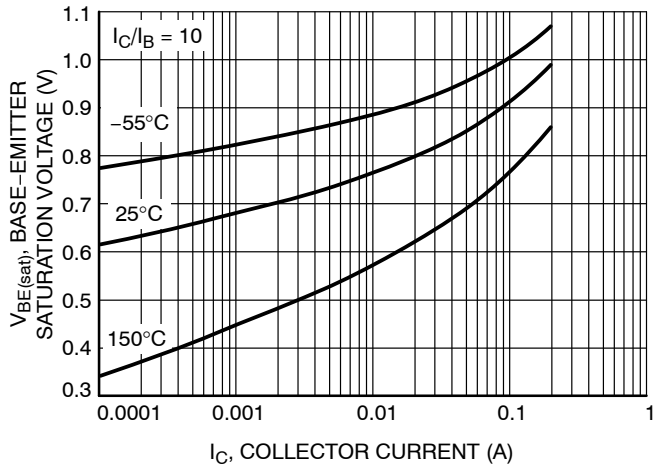


Figure 3. Base Emitter Saturation Voltage vs. Collector Current

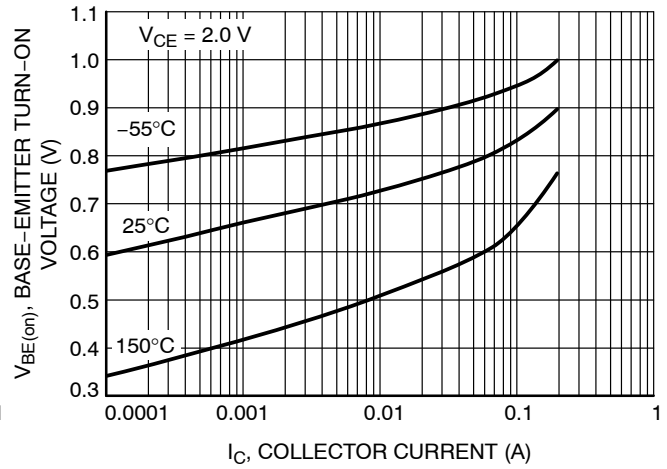


Figure 4. Base Emitter Turn-On Voltage vs. Collector Current

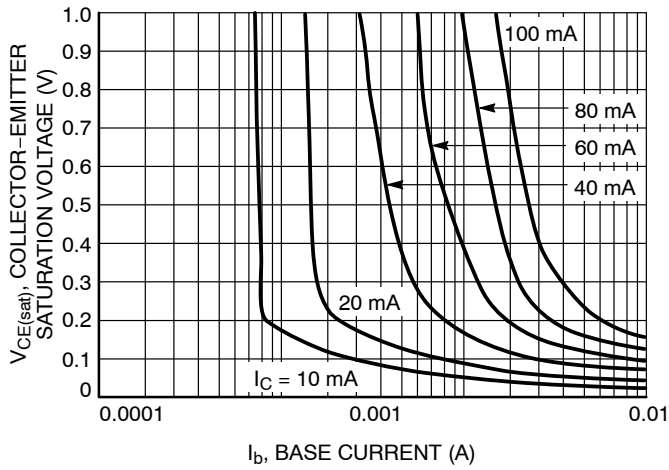


Figure 5. Saturation Region

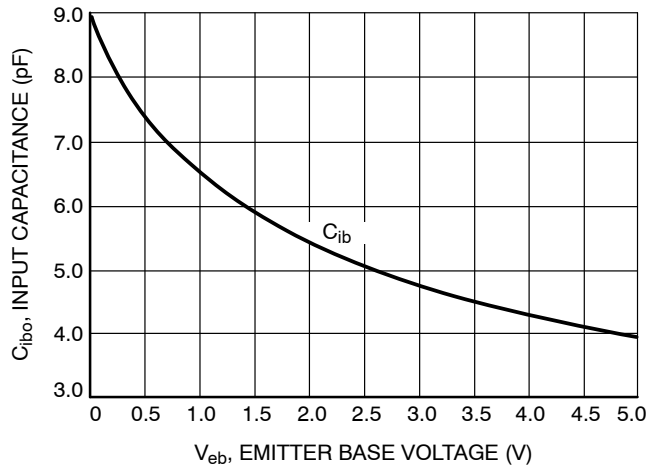


Figure 6. Input Capacitance

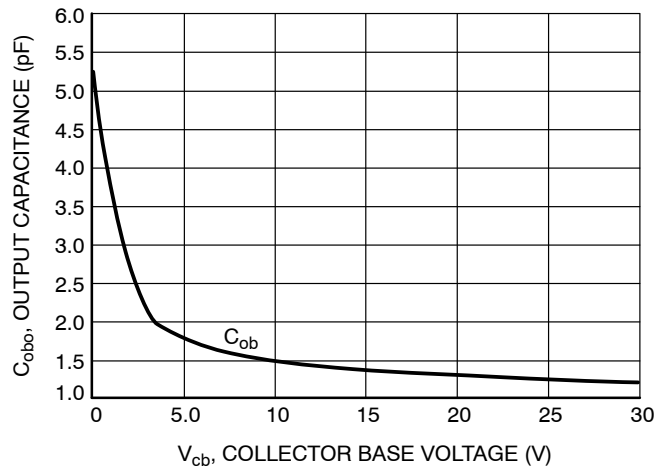
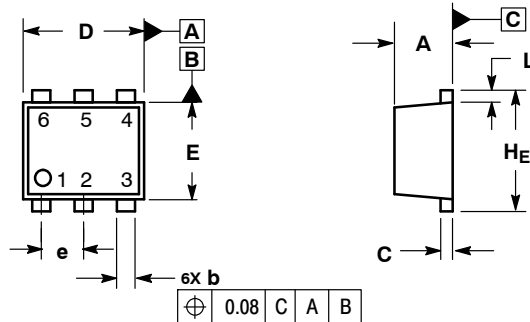


Figure 7. Output Capacitance

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PACKAGE DIMENSIONS

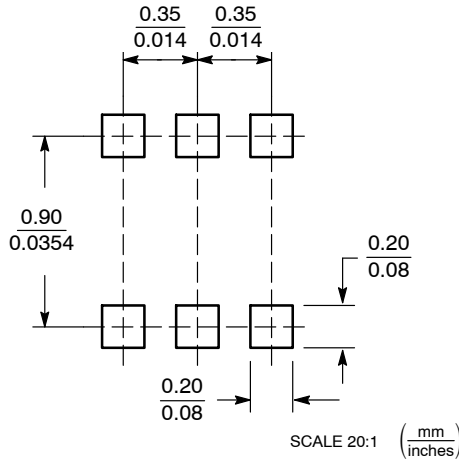
SOT-963
CASE 527AD-01
ISSUE B



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETERS
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.34	0.37	0.40	0.004	0.006	0.008
b	0.10	0.15	0.20	0.003	0.005	0.007
C	0.07	0.12	0.17	0.003	0.005	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
E	0.75	0.80	0.85	0.03	0.032	0.034
e	0.35 BSC			0.014 BSC		
L	0.05	0.10	0.15	0.002	0.004	0.006
H	0.95	1.00	1.05	0.037	0.039	0.041

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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